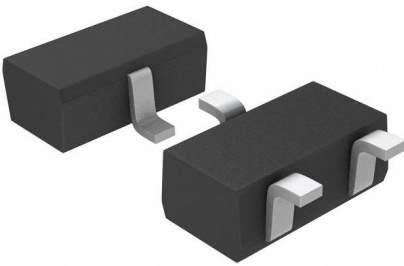


2SC5846G0L Datasheet

www.digi-electronics.com



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DiGi Electronics Part Number	2SC5846G0L-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SC5846G0L
Description	TRANS NPN 50V 0.1A SSSMINI3
Detailed Description	Bipolar (BJT) Transistor NPN 50 V 100 mA 100MHz 100 mW Surface Mount SSSMini3-F2



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:

25C5846G0L

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

50 V

Current - Collector Cutoff (Max):

100µA

Power - Max:

100 mW

Operating Temperature:

125°C (TJ)

Package / Case:

SOT-723

Base Product Number:

25C5846

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Vce Saturation (Max) @ Ib, Ic:

300mV @ 10mA, 100mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

180 @ 2mA, 10V

Frequency - Transition:

100MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SSSMini3-F2

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0075

ECCN:

EAR99

2SC5846G

Silicon NPN epitaxial planar type

For general amplification

■ Features

- High forward current transfer ratio h_{FE}
- SSS-mini type package, allowing downsizing and thinning of the equipment and automatic insertion through the tape packing

■ Package

- Code
SSSMini3-F2
- Marking Symbol: 7K
- Pin Name
 1. Base
 2. Emitter
 3. Collector

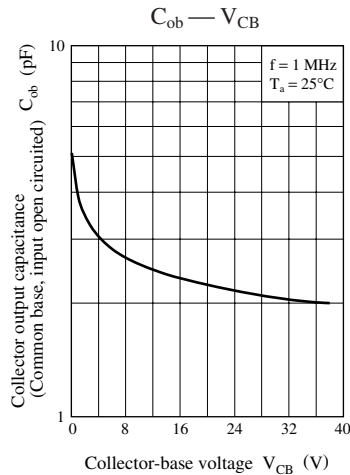
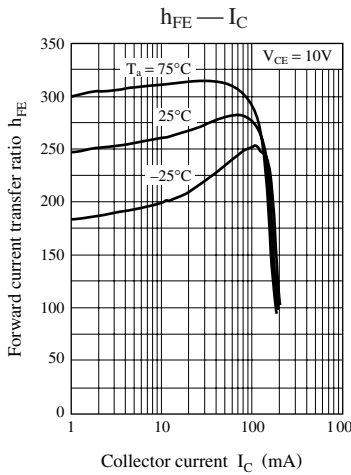
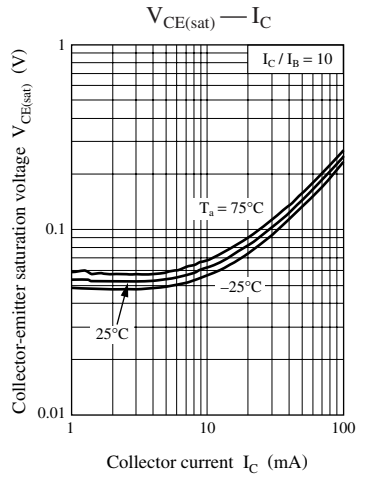
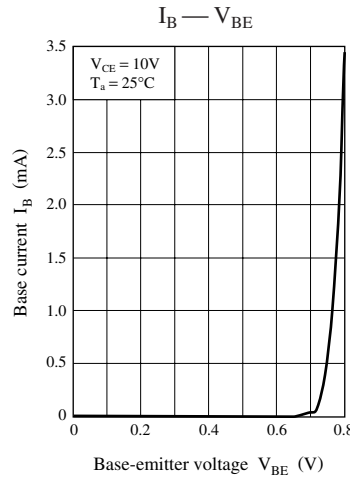
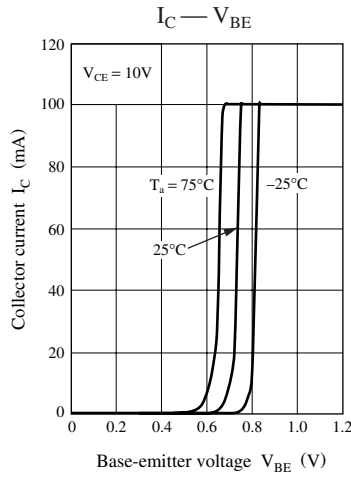
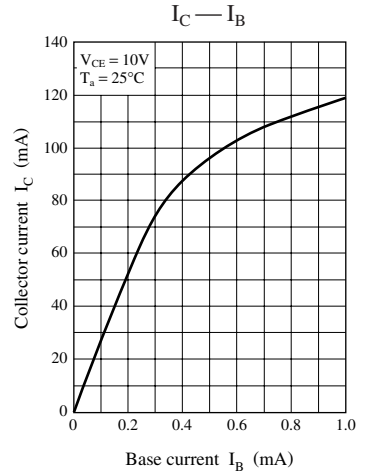
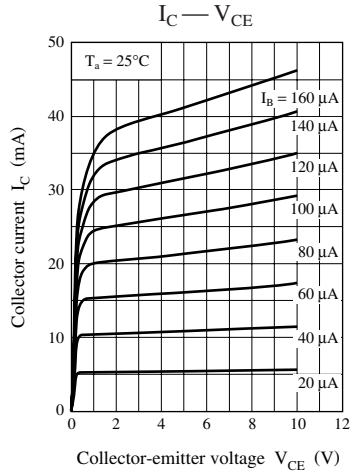
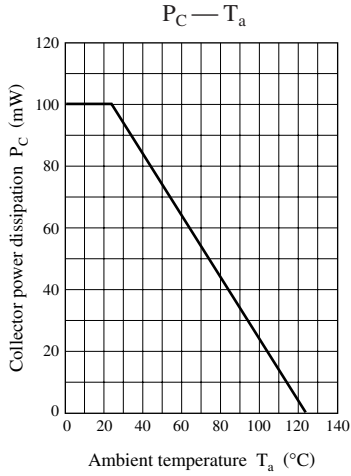
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	60	V
Collector-emitter voltage (Base open)	V_{CEO}	50	V
Emitter-base voltage (Collector open)	V_{EBO}	7	V
Collector current	I_C	100	mA
Peak collector current	I_{CP}	200	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

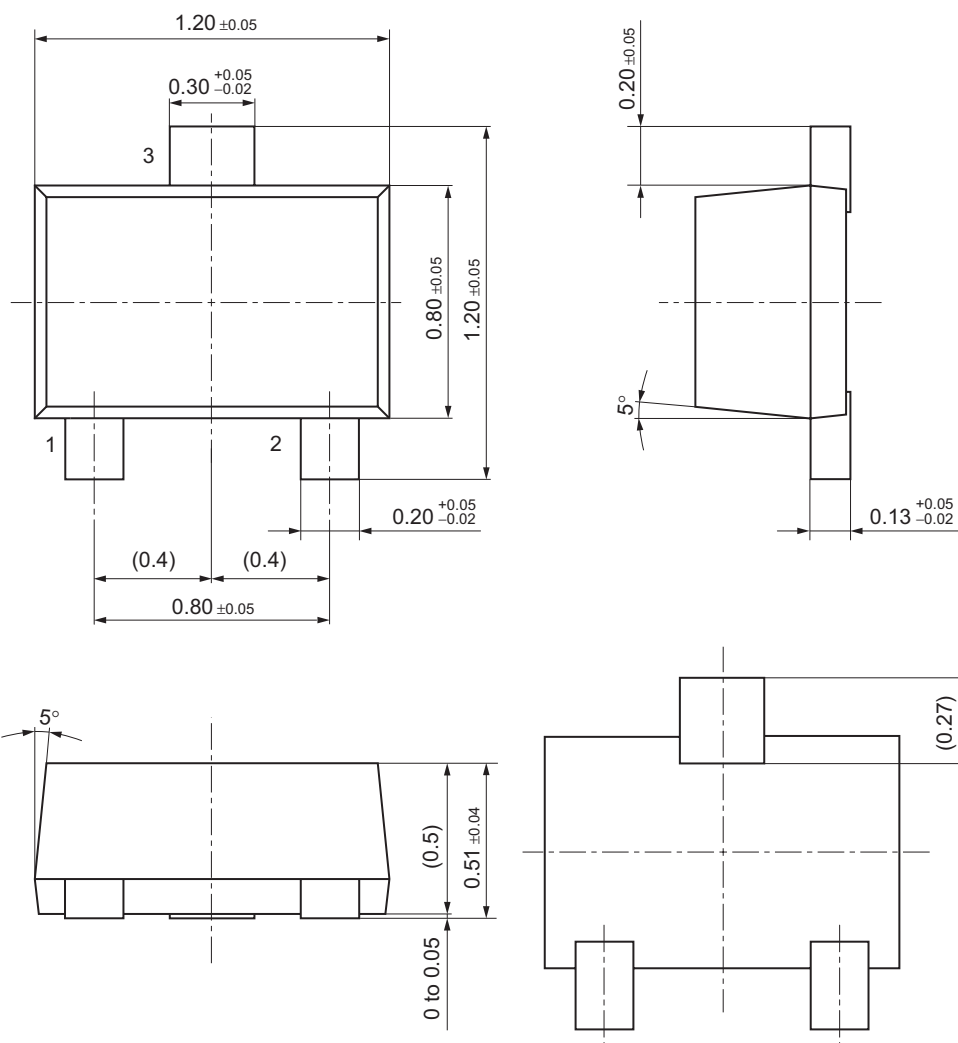
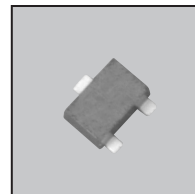
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	60			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	50			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	7			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 10 \text{ V}, I_B = 0$			100	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$	180		390	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$		0.1	0.3	V
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		2.2		pF
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		100		MHz

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



SSSMINI3-F2

Unit: mm



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